TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HC280AP,TC74HC280AF

#### 9-Bit Parity Generator/Checker

The TC74HC280A is a high speed CMOS 9-BIT PARITY GENERATOR fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC280A is composed of nine data inputs A thru I and odd/even parity outputs  $\Sigma$  ODD and  $\Sigma$  EVEN.

The odd parity output is high when an odd number of data inputs are high. The even parity output is high when an even number of data inputs are high.

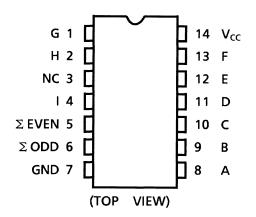
The word-length capability is easily expanded by cascading.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

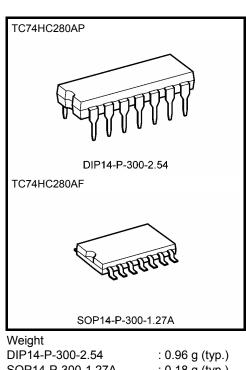
#### Features

- High speed:  $t_{pd} = 22$  ns (typ.) at V<sub>CC</sub> = 5 V •
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$ •
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Output drive capability: 10 LSTTL loads •
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 4 \text{ mA} (\text{min})$
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 6 V
- Pin and function compatible with 74LS280

#### **Pin Assignment**



NC: No connection

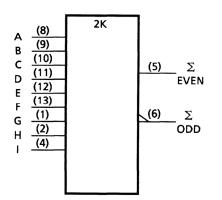


SOP14-P-300-1.27A

: 0.18 g (typ.)

## **TOSHIBA**

### IEC Logic Symbol

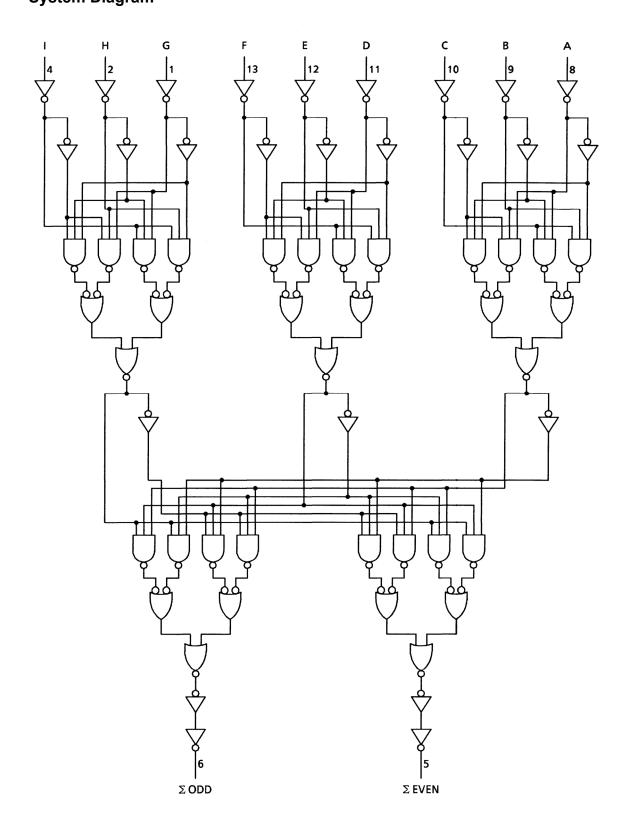


#### **Truth Table**

Number of Inputs A Through I That are High	Outputs				
	$\Sigma$ EVEN	$\Sigma$ ODD			
0, 2, 4, 6, 8	Н	L			
1, 3, 5, 7, 9	L	Н			

# System Diagram

**TOSHIBA** 



#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	–0.5 to 7	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	IOK	±20	mA
DC output current	IOUT	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to  $65^{\circ}$ C. From Ta = 65 to  $85^{\circ}$ C a derating factor of -10 mW/°C shall be applied until 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2 to 6	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 ( $V_{CC} = 6.0 \text{ V}$ )	

#### **Operating Ranges (Note)**

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C		Ta = -40 to 85°C		Unit	
				$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
				2.0	1.50	_	_	1.50	_	
High-level input voltage	VIH	—		4.5	3.15	—	—	3.15	—	V
Ŭ				6.0	4.20			4.20	_	
				2.0		—	0.50	—	0.50	
Low-level input voltage	VIL			4.5	_	—	1.35	—	1.35	V
Ũ				6.0	_	—	1.80	_	1.80	
	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0	1.9	2.0	—	1.9		
			$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	—	4.4	—	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ŭ			I <sub>OH</sub> =4 mA	4.5	4.18	4.31	—	4.13		
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2.0		0.0	0.1	—	0.1	
			$I_{OL} = 20 \ \mu A$	4.5	—	0.0	0.1	—	0.1	
Low-level output voltage	V <sub>OL</sub>			6.0	—	0.0	0.1	—	0.1	V
Ũ			$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	
			I <sub>OL</sub> = 5.2 mA	6.0	—	0.18	0.26	—	0.33	
Input leakage current	IIN	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or	GND	6.0		_	4.0	—	40.0	μΑ

#### AC Characteristics ( $C_L = 15 \text{ pF}$ , $V_{CC} = 5 \text{ V}$ , $Ta = 25^{\circ}C$ , input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub>	—		4	8	ns
	t <sub>THL</sub>					
Propagation delay time	t <sub>pLH</sub>	—		22	35	ns
	t <sub>pHL</sub>					115

### AC Characteristics (C<sub>L</sub> = 50 pF, input: $t_r = t_f = 6$ ns)

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	,		$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
	<b>4</b>		2.0	_	30	75	_	95	
Output transition time	—	4.5	_	8	15	—	19	ns	
	ITHL		6.0	_	7	13	—	16	
	4		2.0	_	80	200	_	250	
Propagation delay time	t <sub>pLH</sub>	—	4.5	_	26	40	—	50	ns
	t <sub>pHL</sub>		6.0	_	22	34	—	43	
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_		_	61	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

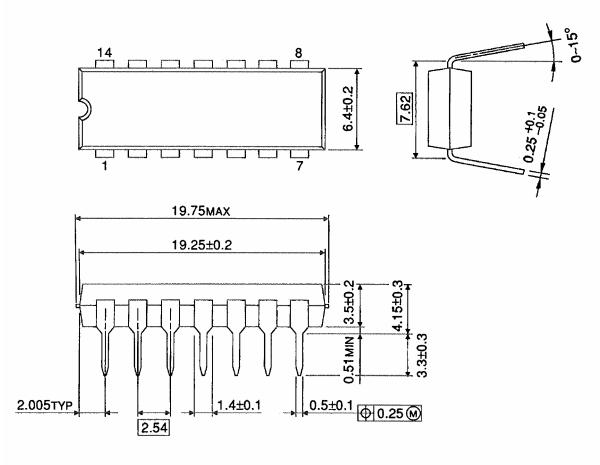
Average operating current can be obtained by the equation:

 $I_{CC} (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **Package Dimensions**

DIP14-P-300-2.54

Unit : mm

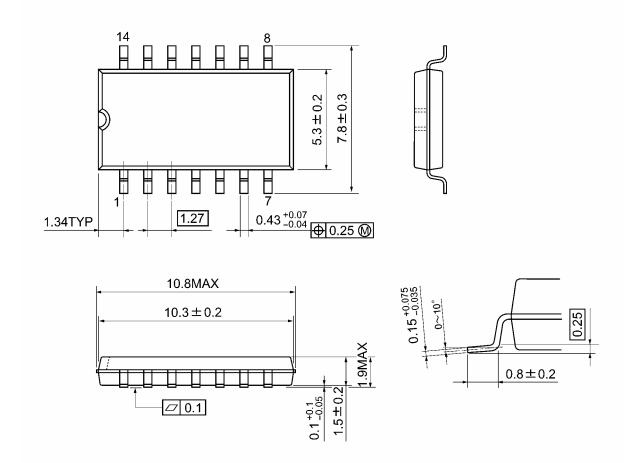


Weight: 0.96 g (typ.)

#### **Package Dimensions**

SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

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20070701-EN GENERAL

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